

4	Application No.	Applicant(s)	
.	9/935,002	RHEE, TAE-POK	
Notice of Allowability Exa	xaminer	Art Unit	
	I.Jey Tsai	2812	
The MAILING DATE of this communication appear All claims being allowable, PROSECUTION ON THE MERITS IS (O herewith (or previously mailed), a Notice of Allowance (PTOL-85) or NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGI of the Office or upon petition by the applicant. See 37 CFR 1.313 a	R REMAINS) CLOSED in other appropriate comm HTS. This application is:	n this application. If not included unication will be mailed in due course. THIS	
1. X This communication is responsive to paper filed on 6/29/05.			
2. ⊠ The allowed claim(s) is/are <u>1-15,25-27,29-40,50 and 51</u> .		·	
<ul> <li>3.  Acknowledgment is made of a claim for foreign priority under a)  All b)  Some* c)  None of the:</li> <li>1.  Certified copies of the priority documents have b</li> <li>2.  Certified copies of the priority documents have b</li> </ul>	een received.		
3. ☐ Copies of the certified copies of the priority documents have be	• •		
International Bureau (PCT Rule 17.2(a)).	nients nave been receive	u iii uiis nauonai stage application nom the	
* Certified copies not received:			
Applicant has THREE MONTHS FROM THE "MAILING DATE" of noted below. Failure to timely comply will result in ABANDONME! THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.  4. A SUBSTITUTE OATH OR DECLARATION must be submitted informal patent application (PTO-152) which gives	NT of this application. ed. Note the attached EX	AMINER'S AMENDMENT or NOTICE OF	
	, ,	r declaration is deficient.	
5. CORRECTED DRAWINGS (as "replacement sheets") must be		/ DTO 049) ottochod	
<ul><li>(a) ☐ including changes required by the Notice of Draftsperson</li><li>1) ☐ hereto or 2) ☐ to Paper No./Mail Date</li></ul>	is Patent Drawing Review	w (P10-948) attached	
(b) ☐ including changes required by the attached Examiner's A	mendment / Comment o	r in the Office action of	
Paper No./Mail Date		Thrute emoc dealer of	
Identifying indicia such as the application number (see 37 CFR 1.84 each sheet. Replacement sheet(s) should be labeled as such in the			
<ol> <li>DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT FO</li> </ol>			
Attachment(s)	_ —		
1. Notice of References Cited (PTO-892)		nformal Patent Application (PTO-152)	
<ol> <li>Notice of Draftperson's Patent Drawing Review (PTO-948)</li> <li>Information Disclosure Statements (PTO-1449 or PTO/SB/08)</li> </ol>	Paper No.	Interview Summary (PTO-413),     Paper No./Mail Date     Examiner's Amendment/Comment	
Paper No./Mail Date			
Examiner's Comment Regarding Requirement for Deposit of Biological Material		Statement of Reasons for Allowance	
or prological Material	9. 🗌 Other		

Application/Control Number: 09/935,002

Art Unit: 2812

## Reasons For Allowance

The following is an Examiner's statement of reasons for the indication of allowable subject matter:

The basis for the allowability is:

Prior art of record does not teach combination of forming a groove in the insulating layer on a semiconductor substrate, forming a conductive layer conductive layer over the insulating layer and groove, patterning the conductive layer to form lower conductive lines slantly longitudinally across the groove, forming a cylindrical insulator from an oxidizable material over the lower conductive lines and protruding from the upper surface of the groove and forming upper conductive lines over the insulator to form a rounded upper conductive lines.

The claimed invention overcome the most pertinent prior arts for the following reasons:

- 1. Prior art: JP '406 teaches forming a groove in the silicon substrate, lower conductive lines and magnetic core or air in the groove but does not teach forming a groove in the insulating layer on a semiconductor substrate, forming lower conductive lines slantly longitudinally across the groove, forming a cylindrical insulator from an oxidizable material over the lower conductive lines and protruding from the upper surface of the groove and forming upper conductive lines over the insulator to form a rounded upper conductive lines.
- 2. Prior art: Yamada et al. 6,236,538 teaches forming a groove in the silicon or glass substrate, lower conductive lines in the groove and a magnetic core material in the groove does not teach forming a groove in the insulating layer on a semiconductor substrate, forming a conductive layer conductive layer over the insulating layer and groove, patterning the conductive layer to form lower conductive lines slantly longitudinally across the groove, forming a cylindrical insulator from an oxidizable material over the lower conductive lines and protruding from the upper surface of the groove and forming upper conductive lines over the insulator to form a rounded upper conductive lines.
- 3. Prior art: Sundaram et al. 5,372,967 teaches forming a groove in a silicon substrate or in an insulating layer, lower conductive lines in the groove and planarizing the cylindrical insulator so that the upper surface is planarized (not protruding) but does not teach forming a groove in the insulating layer on a semiconductor substrate, forming a conductive layer conductive layer over the insulating layer and groove, patterning the conductive layer to form lower conductive lines slantly longitudinally across the groove, forming a cylindrical insulator from an oxidizable material over the lower conductive lines and protruding from the upper surface of the groove and forming upper conductive lines over the insulator to form a rounded upper conductive lines.

Application/Control Number: 09/935,002

Art Unit: 2812

4. Prior art: Lue 5,863,806 teaches forming conductive diffusing lines in the substrate and oxidixing the substrate to form an insulator but does not teach forming a groove in the insulating layer on a semiconductor substrate, forming a conductive layer conductive layer over the insulating layer and groove, patterning the conductive layer to form lower conductive lines slantly longitudinally across the groove, forming a cylindrical insulator from an oxidizable material over the lower conductive lines and protruding from the upper surface of the groove and forming upper conductive lines over the insulator to form a rounded upper conductive lines.

Any comments considered necessary by applicant must be submitted no later than the payment of the Issue Fee and, to avoid processing delays, should preferably **accompany** the Issue Fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance".

Any inquiry of a general nature or clerical matters or relating to the status of this application or proceeding should be directed to the customer service whose telephone number is (703) 308-4357.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to H. Jey Tsai whose telephone number is (571) 272-1684. The examiner can normally be reached on from 7:00 Am to 4:00 Pm., Monday thru Thursday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Michael S. Lebentritt can be reached on (571) 272-1873.

The fax phone number for this Group is 571-273-8300.

hjt

9/9/2005

H. Jéy Tsai Primary Examiner

Patent Examining Group 2800